

**CMLSH05-4**  
**SURFACE MOUNT**  
**LOW  $V_F$**   
**SILICON SCHOTTKY DIODE**



[www.centrasemi.com](http://www.centrasemi.com)

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMLSH05-4 is a 40 volt Schottky Diode packaged in a space saving SOT-563 surface mount case. This PICOmini™ device has been designed for applications requiring a low forward voltage drop.

**PICOmini™**



**SOT-563 CASE**

**MARKING CODE: C54**

**MAXIMUM RATINGS:** ( $T_A=25^\circ\text{C}$ )

Peak Repetitive Reverse Voltage  
 Continuous Forward Current  
 Peak Repetitive Forward Current,  $t_p \leq 1.0\text{ms}$   
 Peak Forward Surge Current,  $t_p = 8.0\text{ms}$   
 Power Dissipation  
 Operating and Storage Junction Temperature  
 Thermal Resistance

**SYMBOL**

$V_{RRM}$  40  
 $I_F$  500  
 $I_{FRM}$  3.5  
 $I_{FSM}$  10  
 $P_D$  250  
 $T_J, T_{stg}$  -65 to +150  
 $\Theta_{JA}$  500

**UNITS**

V  
 mA  
 A  
 A  
 mW  
 $^\circ\text{C}$   
 $^\circ\text{C/W}$

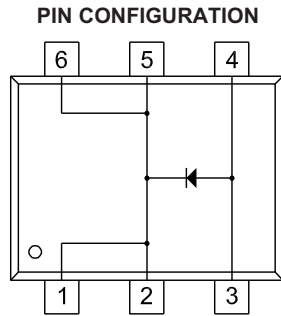
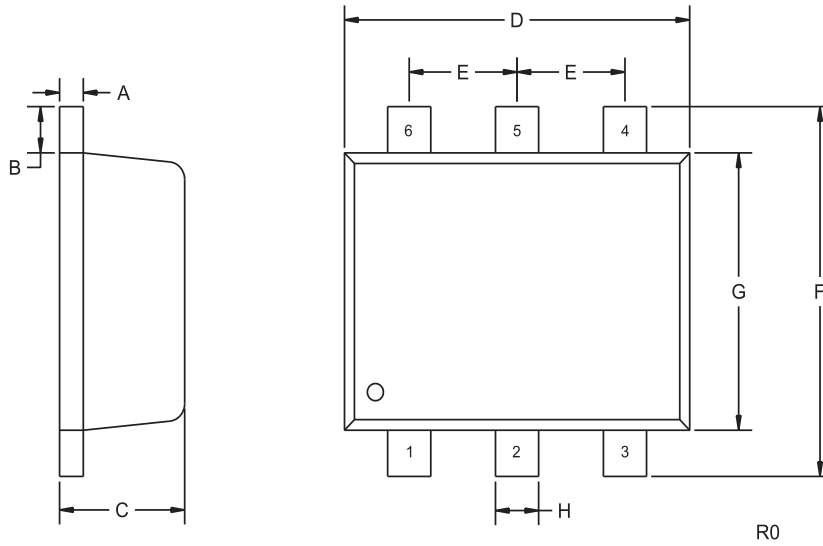
**ELECTRICAL CHARACTERISTICS:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
$I_R$	$V_R=10\text{V}$		20	$\mu\text{A}$
$I_R$	$V_R=30\text{V}$		100	$\mu\text{A}$
$BV_R$	$I_R=500\mu\text{A}$	40		V
$V_F$	$I_F=100\mu\text{A}$		0.13	V
$V_F$	$I_F=1.0\text{mA}$		0.21	V
$V_F$	$I_F=10\text{mA}$		0.27	V
$V_F$	$I_F=100\text{mA}$		0.35	V
$V_F$	$I_F=500\text{mA}$		0.47	V
$C_T$	$V_R=1.0\text{V}, f=1.0\text{MHz}$		50	pF

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**SOT-563 CASE - MECHANICAL OUTLINE**



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.004	0.007	0.10	0.18
B	0.008		0.20	
C	0.022	0.024	0.56	0.60
D	0.059	0.067	1.50	1.70
E	0.020		0.50	
F	0.061	0.067	1.55	1.70
G	0.047		1.20	
H	0.006	0.012	0.15	0.30

SOT-563 (REV: R0)

**LEAD CODE:**

- 1) Cathode
- 2) Cathode
- 3) Anode
- 4) Anode
- 5) Cathode
- 6) Cathode

**MARKING CODE: C54**

R2 (20-January 2010)